

# 10V Drive Nch MOSFET

## R6004CND

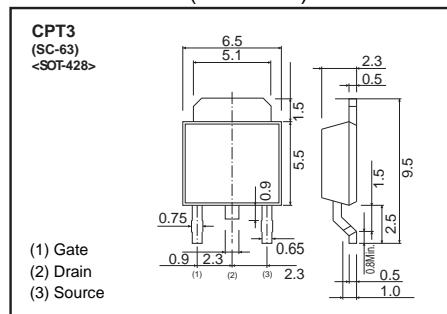
### ● Structure

Silicon N-channel MOSFET

### ● Features

- 1) Low on-resistance.
- 2) High-speed switching.
- 3) Wide SOA.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.

### ● Dimensions (Unit : mm)



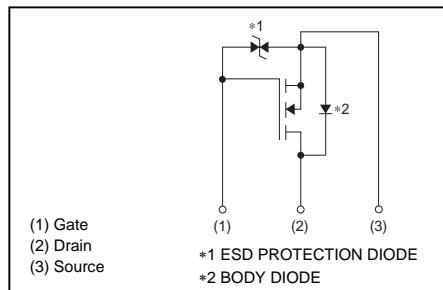
### ● Application

Switching

### ● Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	2500
R6004CND	O	

### ● Inner circuit



### ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	V <sub>DSS</sub>	600	V
Gate-source voltage	V <sub>GSS</sub>	±25	V
Drain current	Continuous I <sub>D</sub> *3	±4	A
	Pulsed I <sub>DP</sub> *1	±16	A
Source current (Body Diode)	Continuous I <sub>S</sub>	4	A
	Pulsed I <sub>SP</sub> *1	16	A
Avalanche current	I <sub>AS</sub> *2	2	A
Avalanche energy	E <sub>AS</sub> *2	1.1	mJ
Power dissipation	P <sub>D</sub> *4	40	W
Channel temperature	T <sub>ch</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

\*1 Pw≤10μs, Duty cycle≤1%

\*2 L=500μH, V<sub>DD</sub>=50V, R<sub>G</sub>=25Ω, T<sub>ch</sub>=25°C

\*3 Limited only by maximum temperature allowed.

\*4 T<sub>C</sub>=25°C

### ● Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to Case	R <sub>th(ch-c)</sub>	3.13	°C / W

## ● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	-	-	±10	μA	V <sub>GS</sub> =±25V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	600	-	-	V	I <sub>D</sub> =1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	-	-	100	μA	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	2.5	-	4.5	V	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA
Static drain-source on-state resistance	R <sub>DS (on)</sub> *	-	1.4	1.8	Ω	I <sub>D</sub> =2A, V <sub>GS</sub> =10V
Forward transfer admittance	Y <sub>fs</sub>  *	1.2	-	-	S	V <sub>DS</sub> =10V, I <sub>D</sub> =2A
Input capacitance	C <sub>iss</sub>	-	280	-	pF	V <sub>DS</sub> =25V
Output capacitance	C <sub>oss</sub>	-	222	-	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	-	15	-	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	-	23	-	ns	V <sub>DD</sub> ≈300V, I <sub>D</sub> =2A
Rise time	t <sub>r</sub> *	-	28	-	ns	V <sub>GS</sub> =10V
Turn-off delay time	t <sub>d(off)</sub> *	-	44	-	ns	R <sub>L</sub> =150Ω
Fall time	t <sub>f</sub> *	-	39	-	ns	R <sub>G</sub> =10Ω
Total gate charge	Q <sub>g</sub> *	-	11	-	nC	V <sub>DD</sub> ≈300V
Gate-source charge	Q <sub>gs</sub> *	-	3	-	nC	I <sub>D</sub> =4A
Gate-drain charge	Q <sub>gd</sub> *	-	5	-	nC	V <sub>GS</sub> =10V

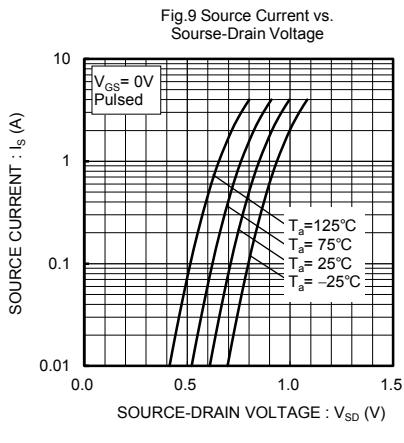
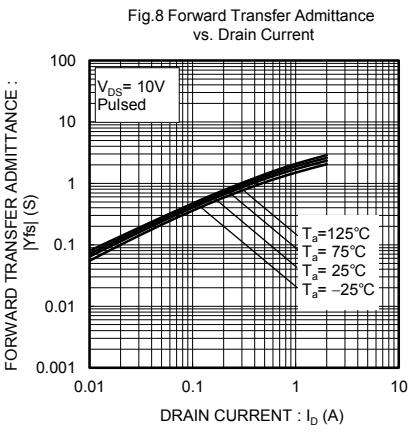
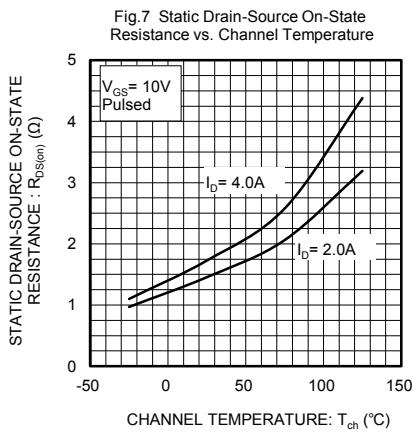
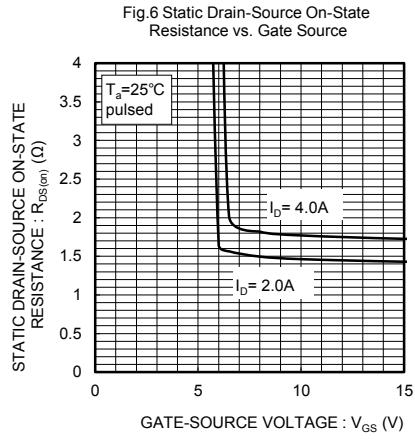
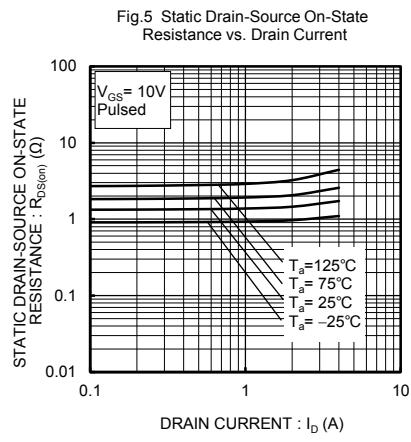
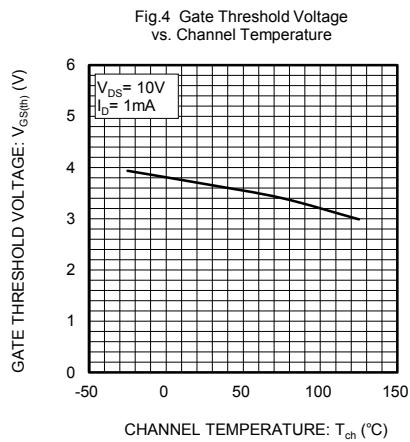
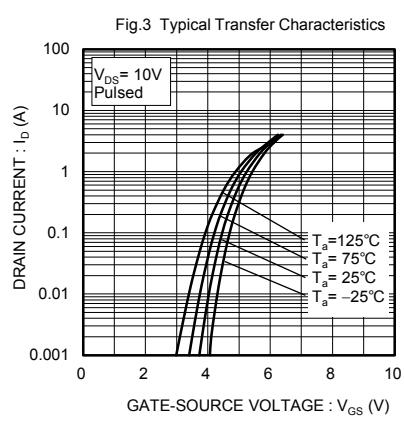
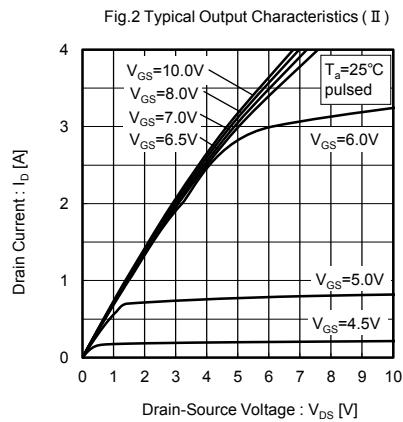
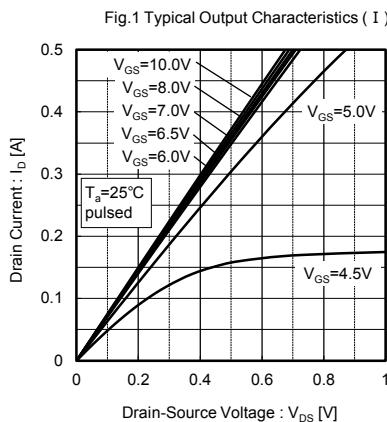
\*Pulsed

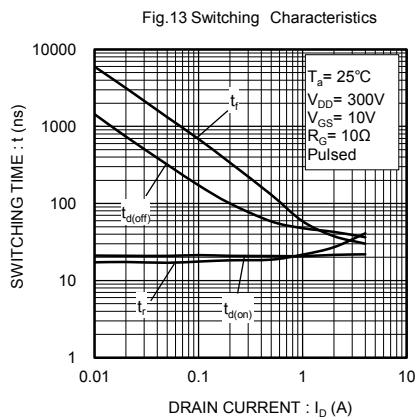
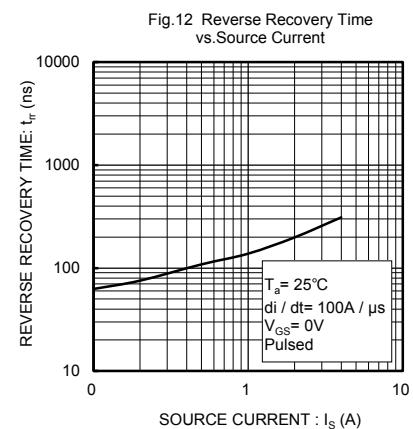
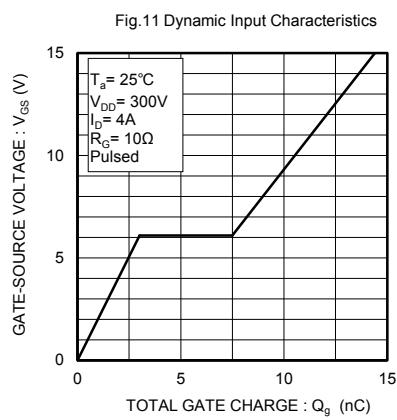
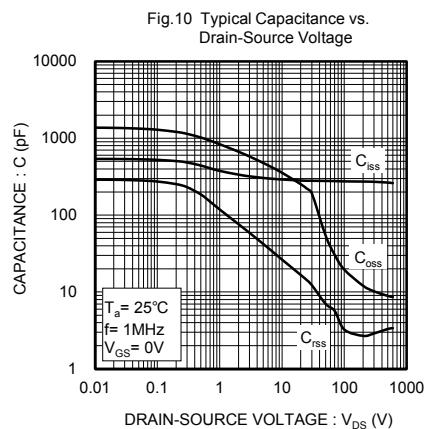
## ● Body diode characteristics (Source-Drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V <sub>SD</sub> *	-	-	1.5	V	I <sub>S</sub> =4A, V <sub>GS</sub> =0V

\*Pulsed

● Electrical characteristic curves





### ● Measurement circuits

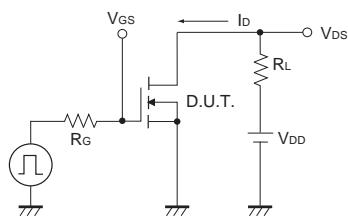


Fig.1-1 Switching Time Measurement Circuit

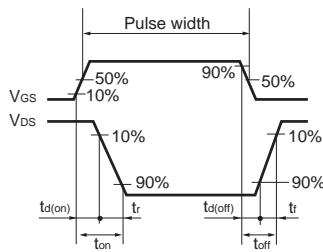


Fig.1-2 Switching Waveforms

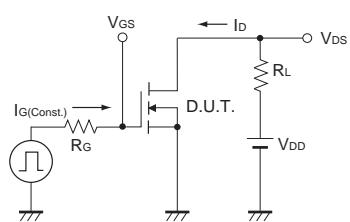


Fig.2-1 Gate Charge Measurement Circuit

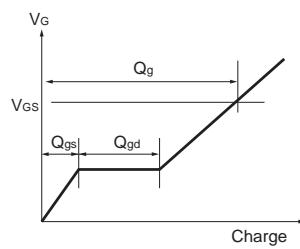


Fig.2-2 Gate Charge Waveform

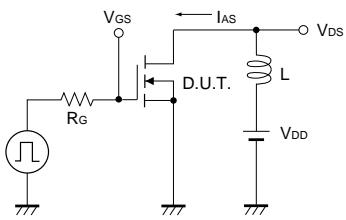


Fig.3-1 Avalanche Measurement Circuit

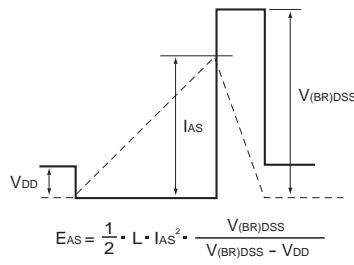


Fig.3-2 Avalanche Waveform

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